NSN 5961-01-475-1016

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-475-1016 **Inclosure Material:** Glass **Overall Length:** Between 0.200 inches and 0.225 inches **Function For Which Designed:** Transient suppressor **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.1 breakdown voltage, dc and 5.7 working peak reverse voltage **Special Features:** 500 watt max. Peak pulse power; e-melf package; square end cap diodes Shelf Life: N/a **Unit Of Measure:** Demilitarization: No